

DESCRIPTION

The 4N29, 4N30, 4N31, 4N32, 4N33 have a gallium arsenide infrared emitter optically coupled to a silicon planar photodarlington.

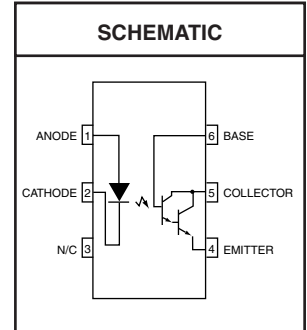
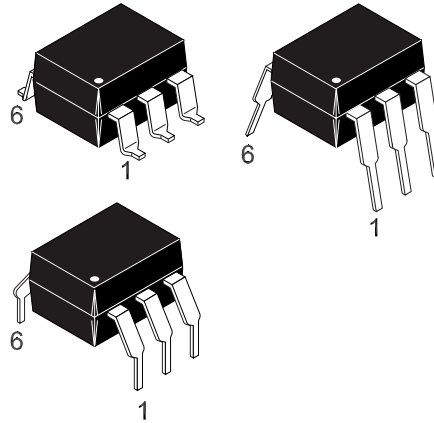
4N29 4N30 4N31 4N32 4N33

FEATURES

- High sensitivity to low input drive current
- Meets or exceeds all JEDEC Registered Specifications
- VDE 0884 approval available as a test option
-add option .300. (e.g., 4N29.300)

APPLICATIONS

- Low power logic circuits
- Telecommunications equipment
- Portable electronics
- Solid state relays
- Interfacing coupling systems of different potentials and impedances.



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C Unless otherwise specified.)

| Parameter | Symbol | Value | Units |
|--|--------------------|----------------|-------|
| TOTAL DEVICE | | | |
| Storage Temperature | T _{STG} | -55 to +150 | °C |
| Operating Temperature | T _{OPR} | -55 to +100 | °C |
| Lead Solder Temperature | T _{SOL} | 260 for 10 sec | °C |
| Total Device Power Dissipation @ T _A = 25°C | P _D | 250 | mW |
| Derate above 25°C | | 3.3 | mW/°C |
| EMITTER | | | |
| Continuous Forward Current | I _F | 80 | mA |
| Reverse Voltage | V _R | 3 | V |
| Forward Current - Peak (300 μs, 2% Duty Cycle) | I _{F(pk)} | 3.0 | A |
| LED Power Dissipation @ T _A = 25°C | P _D | 150 | mW |
| Derate above 25°C | | 2.0 | mW/°C |
| DETECTOR | | | |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | 30 | V |
| Collector-Base Breakdown Voltage | BV _{CBO} | 30 | V |
| Emitter-Collector Breakdown Voltage | BV _{ECO} | 5 | V |
| Detector Power Dissipation @ T _A = 25°C | P _D | 150 | mW |
| Derate above 25°C | | 2.0 | mW/°C |
| Continuous Collector Current | I _C | 150 | mA |

| | | | | |
|-------------|-------------|-------------|-------------|-------------|
| 4N29 | 4N30 | 4N31 | 4N32 | 4N33 |
|-------------|-------------|-------------|-------------|-------------|

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

INDIVIDUAL COMPONENT CHARACTERISTICS

| Parameter | Test Conditions | Symbol | Min | Typ | Max | Unit |
|--------------------------------------|--|------------|-----|-------|-----|---------------|
| EMITTER | | | | | | |
| *Input Forward Voltage | ($I_F = 10\text{ mA}$) | V_F | | 1.2 | 1.5 | V |
| *Reverse Leakage Current | ($V_R = 3.0\text{ V}$) | I_R | | 0.001 | 100 | μA |
| *Capacitance | ($V_F = 0\text{ V}$, $f = 1.0\text{ MHz}$) | C | | 150 | | pF |
| DETECTOR | | | | | | |
| *Collector-Emitter Breakdown Voltage | ($I_C = 100\ \mu\text{A}$, $I_B = 0$) | BV_{CEO} | 30 | 60 | | |
| *Collector-Base Breakdown Voltage | ($I_C = 100\ \mu\text{A}$, $I_E = 0$) | BV_{CBO} | 30 | 100 | | V |
| *Emitter-Collector Breakdown Voltage | ($I_E = 100\ \mu\text{A}$, $I_B = 0$) | BV_{ECO} | 5.0 | 8 | | V |
| *Collector-Emitter Dark Current | ($V_{CE} = 10\text{ V}$, Base Open) | I_{CEO} | | 1 | 100 | nA |
| DC Current Gain | ($V_{CE} = 5.0\text{ V}$, $I_C = 500\ \mu\text{A}$) | h_{FE} | | 5000 | | |

TRANSFER CHARACTERISTICS

| DC Characteristic | Test Conditions | Symbol | Min | Typ | Max | Units |
|---|--|---------------|----------|-----|-----|--------|
| *Collector Output Current ^(1,2) (4N32, 4N33) | (I _F = 10 mA, V _{CE} = 10 V, I _B = 0) | I_C (CTR) | 50 (500) | | | mA (%) |
| (4N29, 4N30) | | | 10 (100) | | | |
| (4N31) | | | 5 (50) | | | |
| *Saturation Voltage ⁽²⁾ (4N29, 4N30, 4N32, 4N33) | (I _F = 8.0 mA, I _C = 2.0 mA) | $V_{CE(sat)}$ | | | 1.0 | V |
| (4N31) | | | | | 1.2 | |

TRANSFER CHARACTERISTICS

| AC Characteristic | Test Conditions | Symbol | Min | Typ | Max | Units |
|---|--|----------|-----|-----|-----|---------------|
| Turn-on Time ⁽³⁾ | (I _F = 200 mA, I _C = 50 mA, V _{CC} = 10 V) (Fig.7) | t_{on} | | | 5.0 | μs |
| Turn-off Time ⁽³⁾ (4N32, 4N33) | | | | | 100 | |
| (4N29, 4N30, 4N31) | | | | | 40 | |
| Bandwidth ^(4,5) | | BW | | 30 | | KHz |

ISOLATION CHARACTERISTICS

| Characteristic | Test Conditions | Symbol | Min | Typ | Max | Units |
|---|--|------------------|------|------------------|-----|----------|
| Input-Output Isolation Voltage ⁽⁶⁾ (4N29, 4N30, 4N31, 4N32, 4N33) | (I _{I-O} ≤ 1 μA , V _{rms} , t = 1 min.) | V_{ISO} | 5300 | | | Vac(rms) |
| * (4N32) | | | VDC | 2500 | | V |
| * (4N33) | | | VDC | 1500 | | |
| Isolation Resistance ⁽⁶⁾ | (V _{I-O} = 500 VDC) | R _{ISO} | | 10 ¹¹ | | Ω |
| Isolation Capacitance ⁽⁶⁾ | (V _{I-O} = \emptyset , f = 1 MHz) | C _{ISO} | | 0.8 | | pf |

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Fig. 1 Output Current vs. Input Current

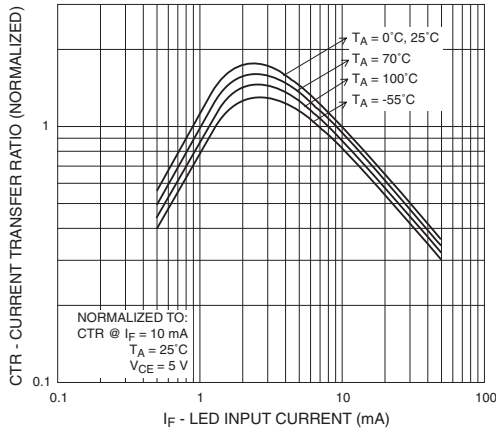


Fig. 2 Current Transfer Ratio vs. Ambient Temperature

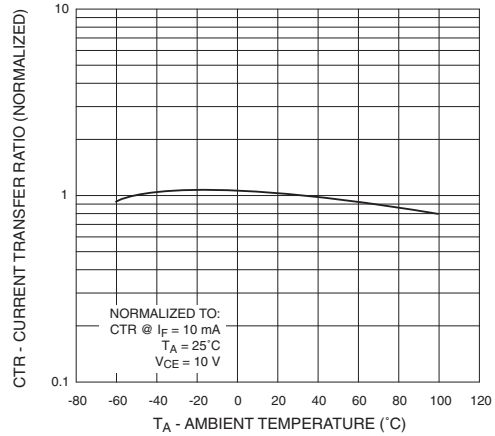


Fig. 3 Collector Current vs. Collector-Emitter Voltage

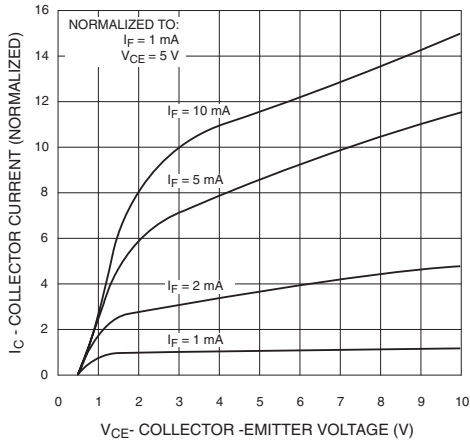


Fig. 4 Dark Current vs. Ambient Temperature

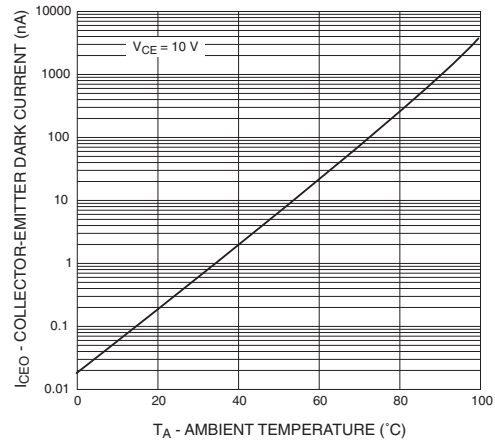


Fig. 5 Turn-On Time vs. Input Current

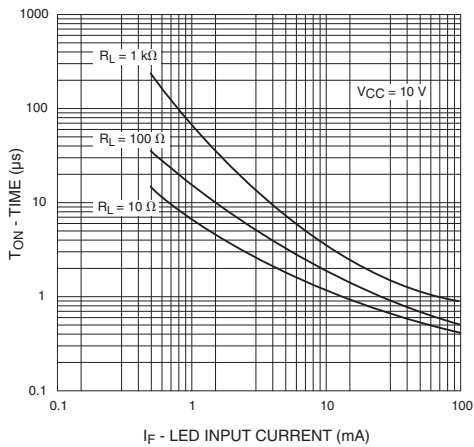
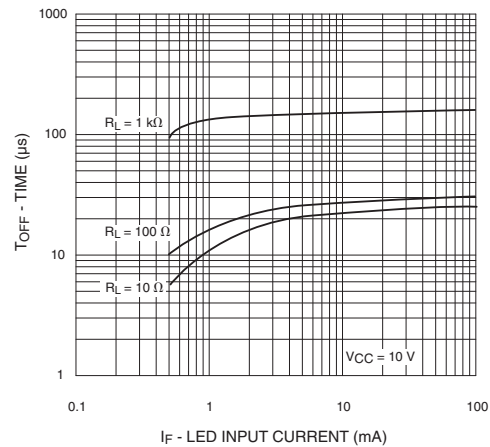


Fig. 6 Turn-Off Time vs. Input Current



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TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVES

(25°C Free air temperature unless otherwise specified) (Cont.)

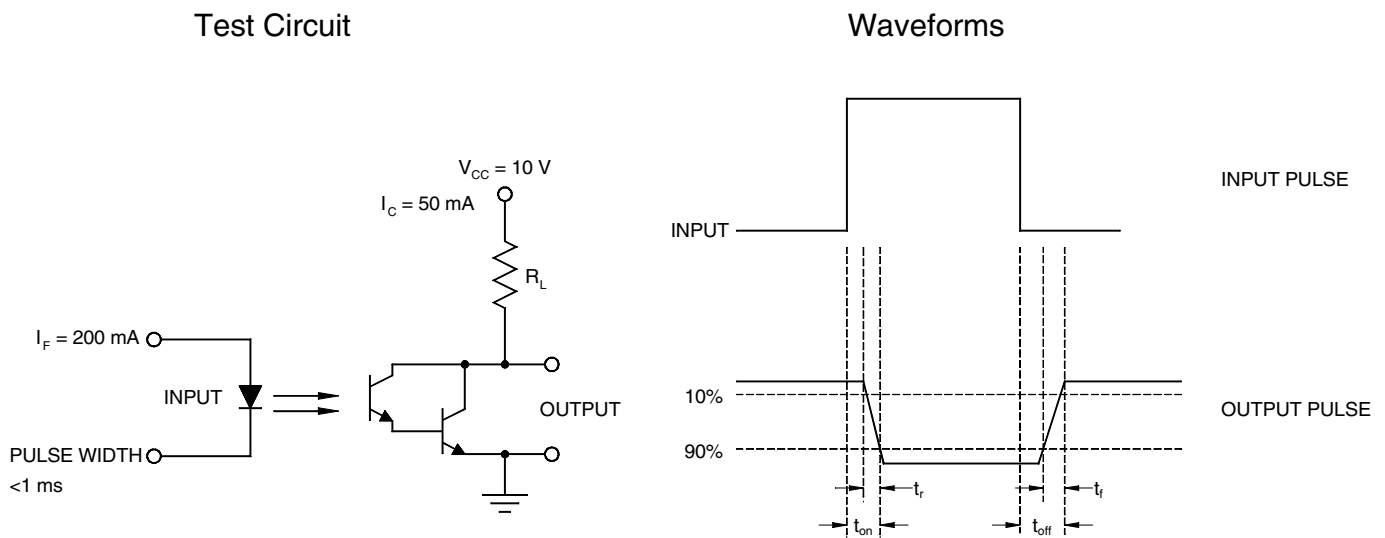


Fig. 7 Switching Time Test Circuit and Waveforms

Notes

* Indicates JEDEC registered data.

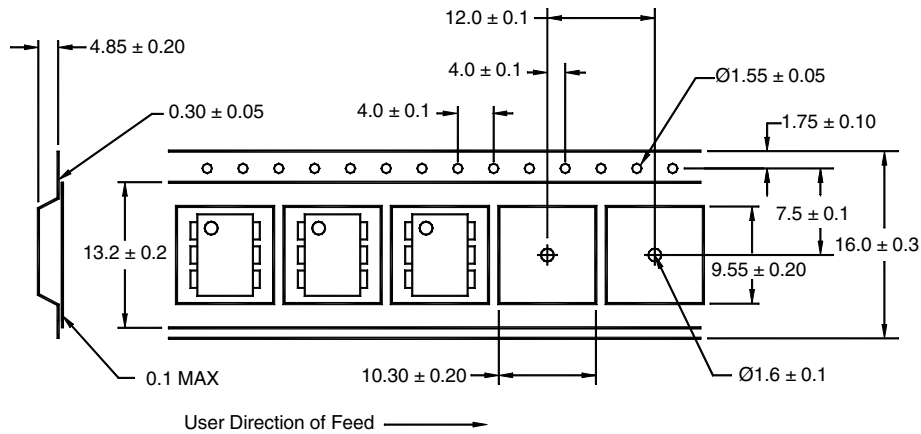
1. The current transfer ratio (I_C/I_F) is the ratio of the detector collector current to the LED input current with $V_{CE} @ 10 \text{ V}$.
2. Pulse test: pulse width = $300 \mu\text{s}$, duty cycle $\leq 2.0\%$.
3. For test circuit setup and waveforms, refer to figure 7..
4. I_F adjusted to $I_C = 2.0 \text{ mA}$ and $I_C = 0.7 \text{ mA rms}$.
5. The frequency at which I_C is 3dB down from the 1 KHz value.
6. For this test, LED pins 1 and 2 are common, and phototransistor pins 4,5 and 6 are common.

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ORDERING INFORMATION

| Option | Order Entry Identifier | Description |
|--------|------------------------|--------------------------------------|
| S | .S | Surface Mount Lead Bend |
| SD | .SD | Surface Mount; Tape and reel |
| W | .W | 0.4" Lead Spacing |
| 300 | .300 | VDE 0884 |
| 300W | .300W | VDE 0884, 0.4" Lead Spacing |
| 3S | .3S | VDE 0884, Surface Mount |
| 3SD | .3SD | VDE 0884, Surface Mount, Tape & Reel |

QT Carrier Tape Specifications ("D" Taping Orientation)



NOTE

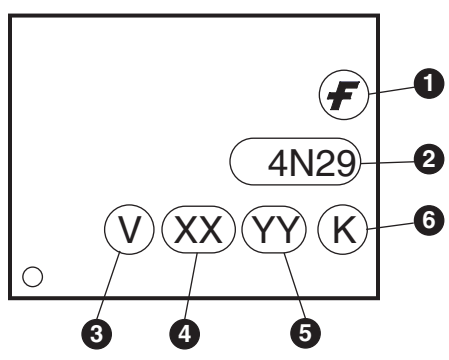
All dimensions are in millimeters

Call QT Optoelectronics for more information or the phone number of your nearest distributor.

United States 800-533-6786 • France 33 [0] 1.45.18.78.78 • Germany 49 [0] 89/96.30.51 • United Kingdom 44 [0] 1296 394499 • Asia/Pacific 603-7248793

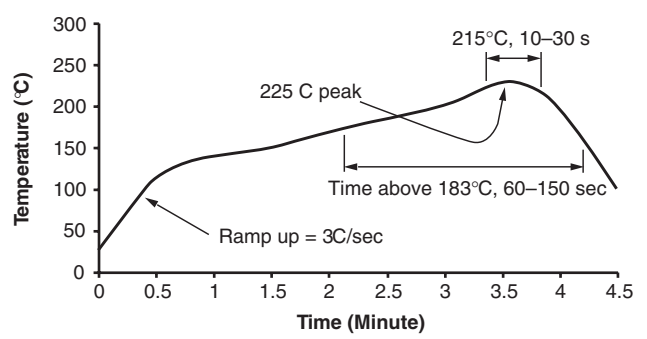
www.qtopto.com

MARKING INFORMATION



| Definitions | |
|-------------|--|
| 1 | Fairchild logo |
| 2 | Device number |
| 3 | VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table) |
| 4 | Two digit year code, e.g., '03' |
| 5 | Two digit work week ranging from '01' to '53' |
| 6 | Assembly package code |

Reflow Profile (Black Package, No Suffix)



- Peak reflow temperature: 225°C (package surface temperature)
- Time of temperature higher than 183°C for 60–150 seconds
- One time soldering reflow is recommended

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| | | | | |
|--------------------------------------|---------------------|---------------|---------------------|-----------------|
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PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|------------------------|---|
| Advance Information | Formative or In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. |
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